TOSHIBA Transistor Silicon NPN Epitaxial Type (PCT process) (darlington)

# 2SD1222

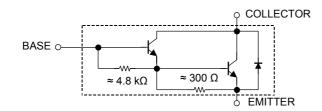
Switching Applications Hammer Drive, Pulse Motor Drive Applications Power Amplifier Applications

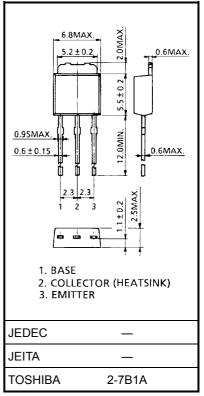
- High DC current gain: hFE = 2000 (min) (VCE = 2 V, IC = 1 A)
- Low saturation voltage: V<sub>CE</sub> (sat) = 1.5 V (max) (I<sub>C</sub> = 2 A)
- Complementary to 2SB907.

## Maximum Ratings (Ta = 25°C)

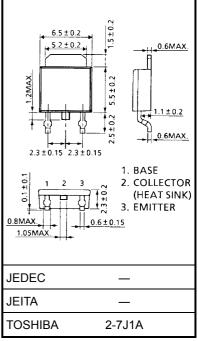
Characteristics		Symbol	Rating	Unit	
Collector-base voltage		V <sub>CBO</sub>	60	V	
Collector-emitter voltage		V <sub>CEO</sub>	40	V	
Emitter-base voltage		V <sub>EBO</sub>	5	V	
Collector current		Ι <sub>C</sub>	3	А	
Base current		Ι <sub>Β</sub>	0.3	А	
Collector power dissipation	Ta = 25°C	Pc	1.0	w	
	Tc = 25°C	ГС	15		
Junction temperature		Тј	150	°C	
Storage temperature range		T <sub>stg</sub>	-55 to 150	°C	







Weight: 0.36 g (typ.)



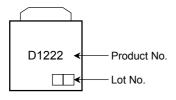
Weight: 0.36 g (typ.)

Unit: mm

**Electrical Characteristics (Ta = 25°C)** 

Characteristics		Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current		I <sub>CBO</sub>	$V_{CB} = 60 V, I_E = 0$	_	_	20	μA
Emitter cut-off current		I <sub>EBO</sub>	V <sub>EB</sub> = 5 V, I <sub>C</sub> = 0			2.5	mA
Collector-emitter breakdown voltage		V (BR) CEO	I <sub>C</sub> = 25 mA, I <sub>B</sub> = 0	40	_	_	V
DC current gain		h <sub>FE (1)</sub>	V <sub>CE</sub> = 2 V, I <sub>C</sub> = 1 A	2000	_	_	
		h <sub>FE (2)</sub>	V <sub>CE</sub> = 2 V, I <sub>C</sub> = 3 A	1000	_	_	
Collector-emitter saturation voltage		V <sub>CE (sat)</sub>	I <sub>C</sub> = 2 A, I <sub>B</sub> = 4 mA	_	_	1.5	V
Base-emitter saturation voltage		V <sub>BE (sat)</sub>	I <sub>C</sub> = 2 A, I <sub>B</sub> = 4 mA	_	_	2.0	V
Switching time	Turn-on time	t <sub>on</sub>	$20 \ \mu s$ $INPUT$ $INPUT$ $IB2$ $V_{CC} \approx 30 \ V$ $I_{B1} = -I_{B2} = 6 \ mA, \ DUTY \ CYCLE \le 1\%$	_	0.1	_	
	Storage time	t <sub>stg</sub>		_	1.0	_	μs
	Fall time	t <sub>f</sub>		_	0.2	_	

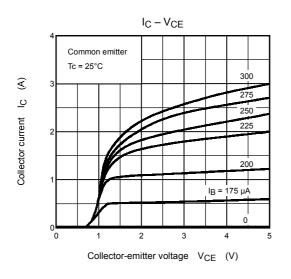
### Marking

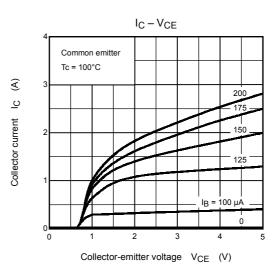


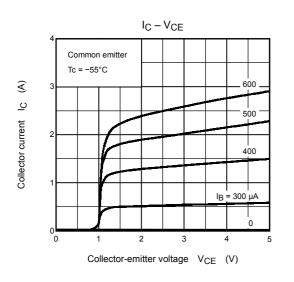
## Explanation of Lot No.

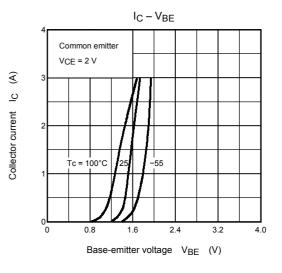
Month of manufacture: January to December are denoted by letters A to L respectively.

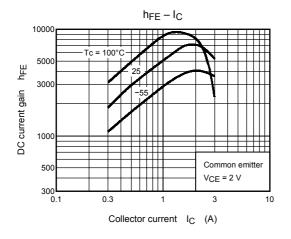
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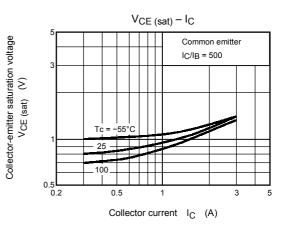




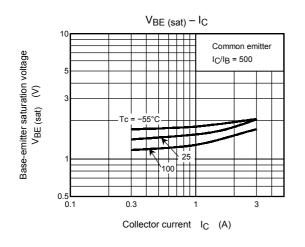


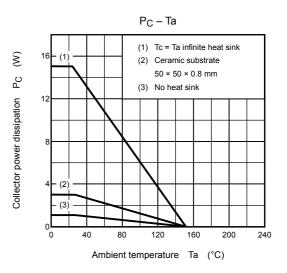


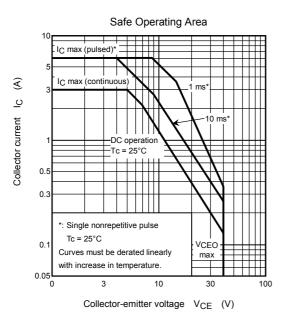




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